

### **General Description**

The DS4106, DS4212, and DS4425 ceramic surfacemount crystal oscillators are part of Maxim's DS4-XO series of crystal oscillators. These devices offer output frequencies at 106.25MHz, 212.5MHz, and 425MHz. The clock oscillators are suited for systems with tight tolerances because of the litter, phase noise, and stability performance. The small package provides a format made for applications where PCB space is critical.

These clock oscillators are crystal based and use a fundamental crystal with PLL technology to provide the final output frequencies. Each device is offered with LVDS or LVPECL output types. The output enable pin is active-high logic.

These clock oscillators have very low phase jitter and phase noise. Typical phase jitter is < 0.9ps RMS from 12kHz to 20MHz. The devices are designed to operate with a 3.3V ±10% supply voltage, and are available in a 5.0mm x 3.2mm x 1.49mm, 10-pin LCCC surface-mount ceramic package.

### **Applications**

Fibre Channel Hard Disk Drives

Host Bus Adapters

Raid Controllers

Fibre Channel Switches

Pin Configuration and Selector Guide appear at end of data sheet.

**Features** 

**♦ Clock Output Frequencies:** DS4106: 106.25MHz DS4212: 212.50MHz DS4425: 425.00MHz

♦ Phase Jitter (RMS): 0.9ps Typical

**♦ LVPECL or LVDS Output** 

**♦ Supply Current:** 

50mA (Typical, Unloaded) at +3.3V Supply (LVPECL)

53mA (Typical) at +3.3V Supply (LVDS)

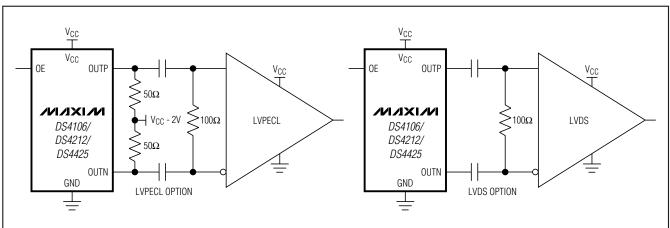
- ♦ -40°C to +85°C Temperature Range
- **♦ Output Disable**

### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
<b>DS4106</b> AN+	-40°C to +85°C	10 LCCC
DS4106BN+	-40°C to +85°C	10 LCCC
<b>DS4212</b> AN+	-40°C to +85°C	10 LCCC
DS4212BN+	-40°C to +85°C	10 LCCC
<b>DS4425</b> AN+	-40°C to +85°C	10 LCCC
DS4425BN+	-40°C to +85°C	10 LCCC

+Denotes a lead-free package. The lead finish is JESD97 category e4 (Au over Ni) and is compatible with both lead-based and lead-free soldering processes.

### **Typical Operating Circuits**



#### **ABSOLUTE MAXIMUM RATINGS**

V <sub>CC</sub> , GND, OE, OUTP, OUTN0.3V, +4V	Storage Temperature Range40°C to +125°C
Operating Temperature Range40°C to +85°C	Soldering Temperature Profile
Junction Temperature+150°C	(3 passes max)See IPC/JEDEC J-STD-020
	Specification

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = 3.0 \text{V to } 3.6 \text{V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}, \text{ typical values are at } V_{CC} = +3.3 \text{V} \text{ and } T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	Vcc	(Note 2)	3.0	3.3	3.6	V
Supply Current	la.	LVPECL (Note 3)		50	65	mA
Supply Current	Icc	LVDS		53	67	IIIA
TTL Control Input-Voltage High (OE)	V <sub>IH</sub>	(Note 2)	2		$V_{CC}$	V
TTL Control Input-Voltage Low (OE)	VIL	(Note 2)	0		0.8	V
Input Leakage Current	lıL	$GND \le OE \le V_{CC}$	-50		+10	μΑ
LVPECL OUTPUTS (Note 4)						
Output High Voltage	VoH	(Note 2)	V <sub>CC</sub> - 1.085		V <sub>CC</sub> - 0.88	V
Output Low Voltage	V <sub>OL</sub>	(Note 2)	V <sub>CC</sub> - 1.825		V <sub>CC</sub> - 1.62	V
Output Leakage Current (Absolute)	loL	OE = V <sub>IL</sub>		100		μА
LVDS OUTPUTS (Figure 2)						
LVDS Output High Voltage	VoH	(Note 2)			1.475	V
LVDS Output Low Voltage	V <sub>OL</sub>	(Note 2)	0.925			V
LVDS Differential Output Voltage	Vod		250		400	
LVDS Change in V <sub>OD</sub> for Complementary States	Δ V <sub>OD</sub>				25	mV
LVDS Offset Output Voltage (Output Common-Mode Voltage)	Vos	(Note 5)	1.125		1.275	V

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = 3.0 \text{V to } 3.6 \text{V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}, \text{ typical values are at } V_{CC} = +3.3 \text{V} \text{ and } T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$  (Note 1)

PARAMETER	SYMBOL	CONDITION	IS	MIN	TYP	MAX	UNITS	
LVDS Change in V <sub>OS</sub> for Complementary States	Δ V <sub>OS</sub>					150	mV	
LVDS Differential Output Impedance	Rolvdso			80		140	Ω	
LVDS Output Current	ILVDSO	Outputs shorted together	er		12		mA	
Output Current	Ivsslvdso	Short to ground				40	mA	
CLOCK OUTPUT								
		DS4106			106.2			
Clock Output Frequency	fO	DS4212			212.5		MHz	
		DS4425			425.0			
Frequency Stability Total	$\Delta f / f_O$	Temperature, aging, load, and supply		-39		+39	ppm	
Initial Frequency Tolerance	f_TOL	+25°C, ±3°C, V <sub>CC</sub> = 3.3V			±20		ppm	
Frequency Stability vs. Temperature	Δf / fo  TA			-30		+30	ppm	
Frequency Stability vs. V <sub>CC</sub>	Δf / f <sub>O</sub>  v	V <sub>CC</sub> = 3.3V ±10%		-3		+3	ppm/V	
Frequency Stability vs. Load	Δf / f <sub>O</sub>	±10% variation in termination resistance			±1		ppm	
Aging (15 Years)	faging			-7		+7	ppm	
Phase Jitter (RMS)	PJ <sub>RMS</sub>	12kHz to 20MHz			0.9		ps	
		10kHz			3			
Accumulated Deterministic		100kHz			27			
Jitter Due to Power-Supply Noise (P-P)		200kHz			15		ps	
		1MHz			7			
Clock Output Edge Speeds	t <sub>R</sub> , t <sub>F</sub>	20% to 80%	LVPECL		200			
Clock Output Edge Speeds		20 /0 10 00 /0	LVDS		175		ps	
Clock Output Duty Cycle		+25°C		45		55	%	
Oscillation Startup Time		(Note 6)			10		ms	

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = 3.0 \text{V to } 3.6 \text{V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}, \text{ typical values are at } V_{CC} = +3.3 \text{V} \text{ and } T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
		DS4106 at 106.25MHz	100Hz		-90		
			1kHz		-112		
			10kHz		-115		
			100kHz		-123		
			1MHz		-142		
			10MHz		-147		
		DS4212 at 212.50MHz	100Hz		-82		dBC/Hz
			1kHz		-106		
Cleak Output CCD Dhaga Naisa			10kHz		-109		
Clock Output SSB Phase Noise			100kHz		-117		
			1MHz		-136		
			10MHz		-141		
		DS4425 at 425.00MHz	100Hz		-76		
			1kHz		-100		
			10kHz		-103		
			100kHz		-111		
			1MHz		-130		]
			10MHz		-135		

**Note 1:** Limits at -40°C are guaranteed by design and are not production tested.

Note 2: Voltage referenced to ground.

Note 3: Outputs are enabled and unloaded.

Note 4: When the LVPECL output is disabled, the typical output off current is < 100μA for nominal LVPECL signal levels at the output.

**Note 5:** AC parameters are guaranteed by design and characterization.

Note 6: Including oscillator startup time and PLL acquisition time, measured after V<sub>CC</sub> reaches 3.0V from power-on.

### **Pin Description**

PIN	NAME	FUNCTION
1	OE	Output Enable. On-chip pullup resistor. Connect OE to logic-high, V <sub>CC</sub> , or leave open to enable the output clock. Connect OE to logic-low or GND to disable the output clock. The LVPECL output clock is set to high impedance when disabled. The LVDS output clock is latched to a differential high when disabled.
2, 7–10	N.C.	No Connection
3	GND	Ground
4	OUTP	Positive Clock Output, LVPECL or LVDS
5	OUTN	Negative Clock Output, LVPECL or LVDS
6	Vcc	+3.3V Supply
_	EP	Exposed Paddle. The exposed pad must be used for thermal relief. This pad can be connected to ground.

### **Detailed Description**

The DS4106/DS4212/DS4425 combine a crystal and an IC to form a precision clock. Figure 1 shows a functional diagram of the devices. The IC consists of a crystal oscillator, a low-noise PLL, selectable clock-divider circuitry, and an output buffer. The PLL consists of a digital phase/frequency detector (PFD) and low-jitter generation VCO. The VCO signal is scaled by a clock-divider circuit and applied to the output buffer.

#### **Output Drivers**

All devices are available with either LVPECL (DS4106A/DS4212A/DS4425A) or LVDS (DS4106B/DS4212B/DS4425B) output buffers. When not needed, the output buffers can be disabled. When disabled, the LVPECL output buffer goes to a high-impedance state. However, the LVDS outputs go to a differential logic one (OUTP latched high and OUTN latched low) when the outputs are disabled.

#### **Additional Information**

For more available frequencies, refer to the DS4125 data sheet at **www.maxim-ic.com/DS4125**.

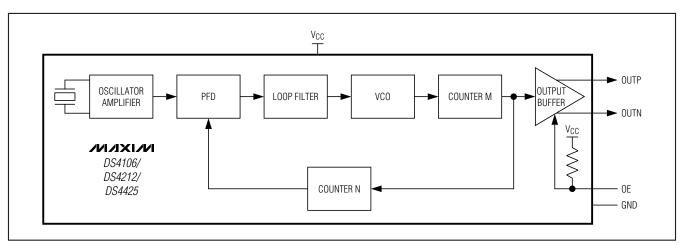


Figure 1. Functional Diagram

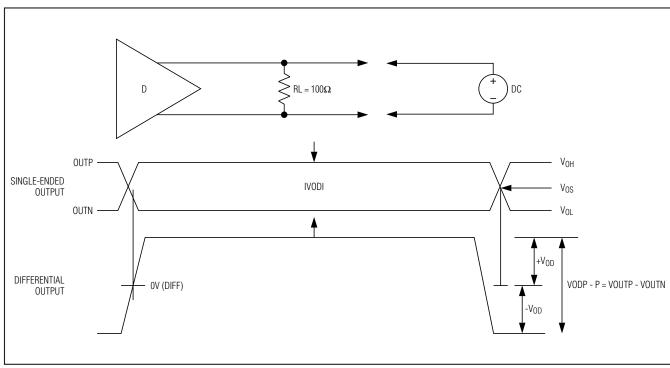


Figure 2. LVDS Level Definitions

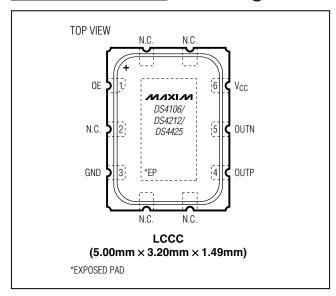
#### **Selector Guide**

PART	OUTPUTS	FREQUENCY (MHz)	TOP MARK
<b>DS4106</b> AN+	LVPECL	106.25	06A
DS4106BN+	LVDS	106.25	06B
<b>DS4212</b> AN+	LVPECL	212.50	12A
DS4212BN+	LVDS	212.50	12B
<b>DS4425</b> AN+	LVPECL	425.00	42A
DS4425BN+	LVDS	425.00	42B

<sup>+</sup>Denotes a lead-free package. The lead finish is JESD97 category e4 (Au over Ni) and is compatible with both lead-based and lead-free soldering processes.

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### **Pin Configuration**



#### Thermal Information

THETA-JA (°C/W)	
90	

### **Package Information**

(For the latest package outline information go to <a href="https://www.maxim-ic.com/DallasPackInfo">www.maxim-ic.com/DallasPackInfo</a>.)

PACKAGE TYPE	DOCUMENT NO.
10 LCCC	56-G5032-002

**Revision History** 

Pages changed at Rev 1: 1, 2, 3

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